

FEATURES

- 2). Hermetic metal case with glass insulator
- 3). Threaded stud ISO M6 or UNF 1/4-28
- 4). International standard case

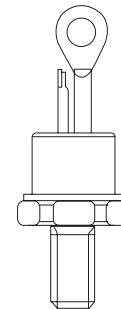
MAJOR RATINGS AND CHARACTERISTICS

V_{RSM}	V_{RRM}, V_{DRM}	$I_{TRMS}=40A$ (maximum value for continuous operation) $I_{TAV}=16A$ (sin. 180° ; $T_C=104^\circ C$)
V	V	
500	400	SKT 16/04D
700	600	SKT 16/06D ^{1)*}
900	800	SKT 16/08D
1300	1200	SKT 16/12E ^{1)*}
1500	1400	SKT 16/14E
1700	1600	SKT 16/16E
1900	1800	SKT 16/18E

1)* Available with UNF thread 1/4-28 UNF2A, e.g. SKT 16/06D UNF

TYPICAL APPLICATIONS

- 1). DC motor control (e.g. for machine tools)
- 2). Controlled rectifiers (e.g. for battery charging)
- 3). AC controllers (e.g. for temperature control)
- 4). Recommended snubber network:
e.g. for $V_{VRMS} \leq 400V$: $R=100\Omega/5W$, $C=0.1\mu F$



ELECTRICAL SPECIFICATIONS

Symbol	Conditions	Values	V
I_{TAV}	sin. 180; $T_C=100(85)^\circ C$	18(23)	A
I_D	K5; $T_a=45^\circ C$; B2/B6	18/24	A
	K3; $T_a=45^\circ C$; B2/B6	24/33	A
I_{RSM}	K5; $T_a=45^\circ C$; W1C	20	A
I_{TSM}	$T_{vj}=25^\circ C$; 10ms	370	A
	$T_{vj}=130^\circ C$; 10ms	330	A
I^2t	$T_{vj}=25^\circ C$; 8,35 ... 10ms	680	A ₂ S
	$T_{vj}=130^\circ C$; 8,35 ... 10ms	550	A ₂ S
V_T	$T_{vj}=25^\circ C$; $I_T=75A$	max. 2.4	V
$V_{T(TO)}$	$T_{vj}=130^\circ C$	max. 1	V
r_T	$T_{vj}=130^\circ C$	max. 20	m Ω
$I_{DD}; I_{RD}$	$T_{vj}=130^\circ C$; $V_{RD}=V_{RRM}$; $V_{DD}=V_{DRM}$	max. 8	mA
t_{gd}	$T_{vj}=25^\circ C$; $I_G=1A$; $di_G/dt=1A/\mu s$	1	μs
t_{gr}	$V_D=0.67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj}=130^\circ C$	max. 50	A/ μs
$(dv/dt)_{cr}$	$T_{vj}=130^\circ C$; SKT ... D/SKT ... E	max. 500/1000	V/ μs
t_q	$T_{vj}=130^\circ C$	80	μs
I_H	$T_{vj}=25^\circ C$; typ./max.	80/150	mA
I_L	$T_{vj}=25^\circ C$; typ./max.	150/300	mA

Symbol	Conditions	Values	V
V_{GT}	$T_{vj}=25^{\circ}\text{C}$; d.c.	min.3	V
I_{GT}	$T_{vj}=25^{\circ}\text{C}$; d.c.	min.100	mA
V_{GD}	$T_{vj}=130^{\circ}\text{C}$; d.c.	max.0.25	V
I_{GD}	$T_{vj}=130^{\circ}\text{C}$; d.c.	max.3	mA
$R_{th(j-c)}$	cont.	0.8	K/W
$R_{th(j-c)}$	sin.180	0.9	K/W
$R_{th(j-c)}$	rec.120	0.95	K/W
$R_{th(c-s)}$		0.5	K/W
T_{vj}		-40 ... +130	$^{\circ}\text{C}$
T_{stg}		-40 ... +150	$^{\circ}\text{C}$
V_{isol}		-	V~
M_s	to heatsink	2.5	Nm
a		5*9.81	m/s^2
m	approx.	13	g
Case		B2	

PERFORMANCE CURVES FIGURE

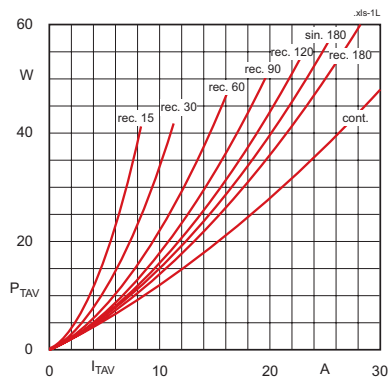


Fig. 1L Power dissipation vs. on-state current

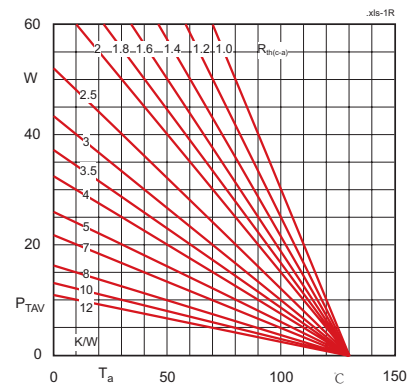


Fig. 1R Power dissipation vs. ambient temperature

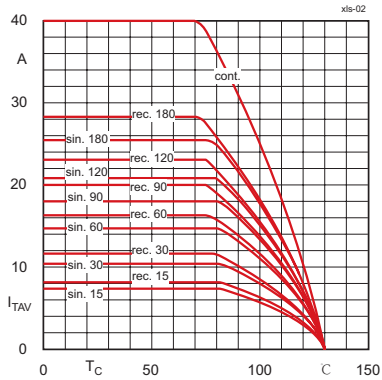


Fig. 2 Rated on-state current vs. case temperature

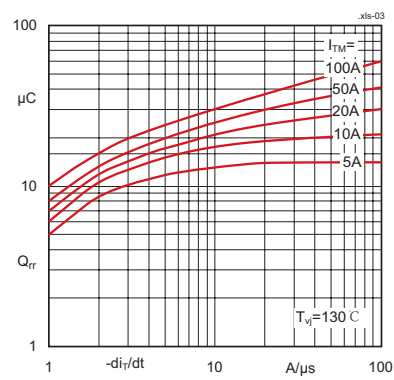


Fig. 3 Recovered charge vs. current decrease

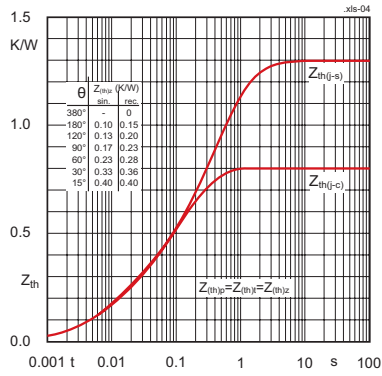


Fig. 4 Transient thermal impedance vs. time

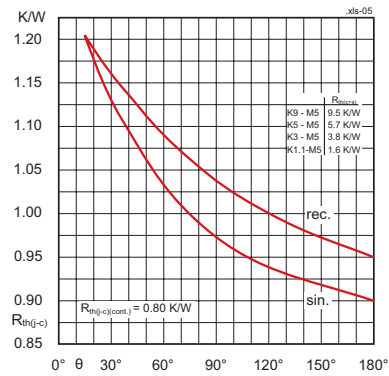


Fig. 5 Thermal resistance vs. conduction angle

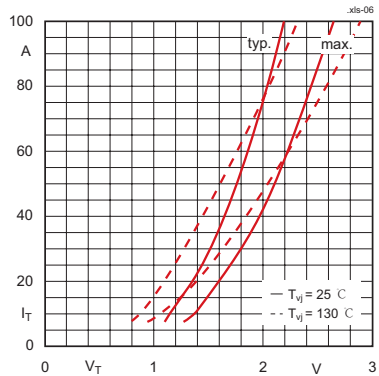


Fig. 6 On-state characteristics

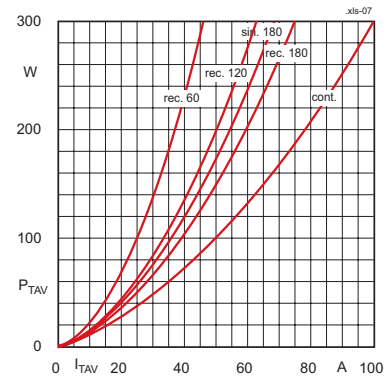


Fig. 7 Power dissipation vs. on-state current

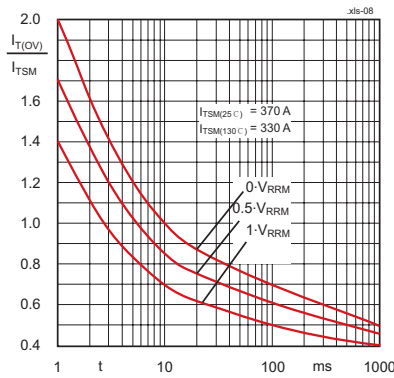


Fig. 8 Surge overload current vs. time

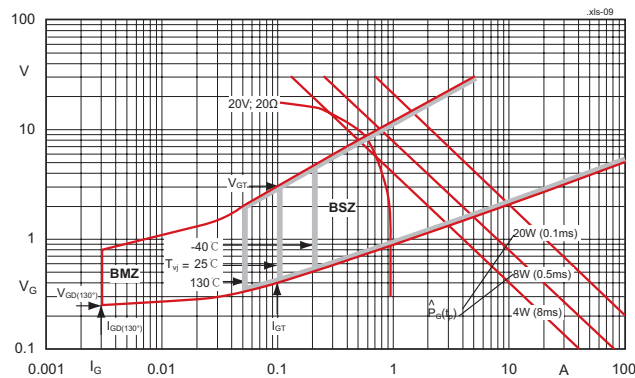
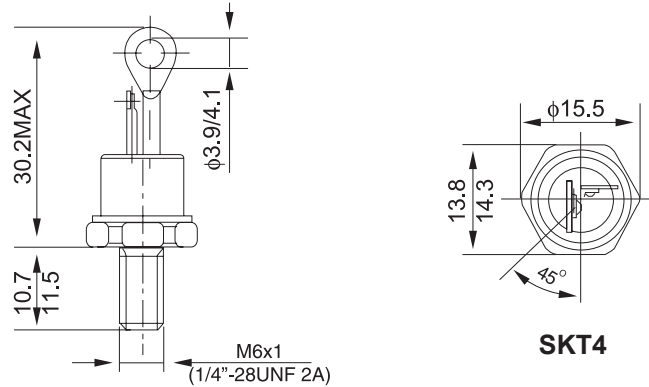


Fig. 9 Gate trigger characteristics

OUTLINE



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